

Technical Data

Green Products

Data Sheet N1255, Rev. -

SDURB/D/F1520 ULTRAFAST PLASTIC RECTIFIER

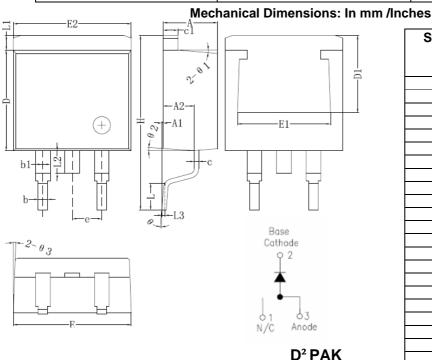
Applications:

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features:

- **Ultra-Fast Switching**
- **High Current Capability**
- **Low Reverse Leakage Current**
- **High Surge Current Capability**
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request





Symbol	Dimensions in			
	millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
e	0	-	8°	
e1		5°		
e2		4°		
e3		4°		

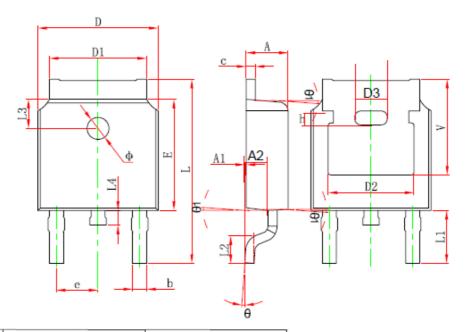
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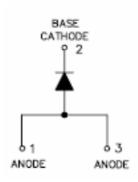




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Symbol	Dimensions In Millimeters		Dimensions In Inches	
Syllibol	Min.	Max.	Min.	Max.
Α	2.200	2.380	0.087	0.094
A10.000	0.000	0.100	0.000	0.004
b	0.710	0.810	0.028	0.032
С	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
D2	4.830	REF.	0.190	REF.
E	6.000	6.200	0.236	0.244
e	2.186	2.386	0.086	0.094
L	9.800	10.400	0.386	0.409
L1	2.900	REF.	0.114	REF.
L2	1.400	1.700	0.055	0.067
L3	1.600	1.600 REF.		REF.
L4	0.600	1.000	0.024	0.039
Φ	1.100	1.300	0.043	0.051
θ	0°	8°	0°	8°
A2	0.910	1.110	0.036	0.044
V	5.350 REF.		0.211	REF.
D3	1.778REF.		0.070	REF.
h	0.762REF.		0.030	REF.
θ1	7°		7	•

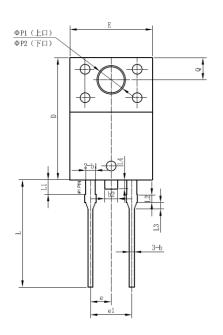


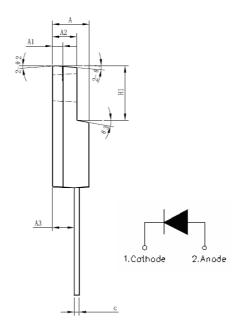
DPAK





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SYMBOL	BOL MIN. TYP.		MAX.	
Α	4.30	4.50	4.70	
A1	1.10	1.30	1.50	
A2 A3	2.80	3.00 2.70	3.20 2.90	
A3	2.50	2.70	2.90	
b	0.50	0.60	0.75	
b1	1.10	1.20	0.75 1.35	
b2	1.50	1.60	1.75	
С	0.55	0.60	0.75	
D	14.80	15.00	15.20	
E	9.96	10.16	10.36	
е		10.16 2.55	-	
e1		5.10	-	
H1	6.50	6.70	6.90	
L	12.70	13.20	13.70	
L1	1.60	1.80	2.00	
L2 L3	0.80	1.00	2.00 1.20 1.00	
L3	0.60	0.80	1.00	
L4	-	1.10	1.50	
ΦP1(上口)	3.30	3.50	3.70 3.39	
ΦP2(下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

2-04

ITO-220AC(HD)

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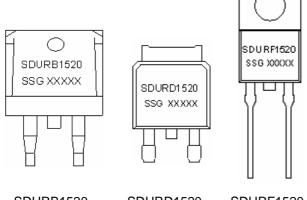
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Marking Diagram:



Where XXXXX is YYWWL

SDUR = Device Type B/D/F = Package type

15 = Forward Current (15A) 20 = Reverse Voltage (200V)

SSG = SSG ΥY = Year WW = Week = Lot Number

SDURB1520

SDURD1520

SDURF1520

Cautions: Molding resin

Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
SDURB1520	D² PAK (Pb-Free)	800pcs/ reel
SDURD1520	DPAK (Pb-Free)	2500pcs/ reel
SDURF1520	ITO-220AC (Pb-Free)	50 pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	200	V
Max. Average Forward Current	I _{F (AV)}	50% duty cycle @Tc=75℃, rectangular wave form	15	Α
Max. Peak One Cycle Non- Repetitive Surge Current (Per leg)	I _{FSM}	8.3ms, Half Sine pulse	110	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	V _F	@15A, Pulse, T _J = 25°C	1.05	V
	V_{F2}	@15A, Pulse, T _J = 150°C	0.85	V
Reverse Current*	I _{R1}	$@V_R = rated V_R$	10	μA
		$T_J = 25^{\circ}C$		
	I _{R2}	$@V_R = rated V_R$	500	uA
		$T_{J} = 150^{\circ}C$		
Reverse Recovery Time	t _{rr}	I_F =500mA, I_R =1A,and I_{rm} =250mA	35	ns

^{*} Pulse width $< 300 \mu s$, duty cycle < 2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	SDURB1520	SDURD1520	SDURF1520	Units
Junction Temperature	T_J		-55 to +150		
Storage Temperature	T _{stg}		-55 to +150		
Maximum Thermal Resistance Junction to Case(per leg)*	$R_{ heta JC}$	2.3	1.7	4.2	K/W
Approximate Weight	wt	1.85	0.39	1.8	g
Case Style		D ² PAK/ DPAK/ ITO-220AC			

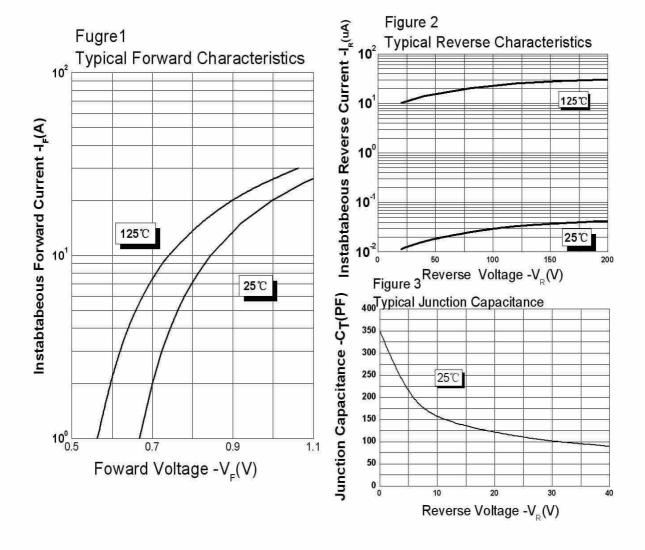
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